

TIP145T/146T/147T

SemiHow
Know-How for Semiconductor

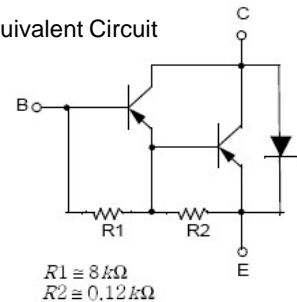
TIP145T/146T/147T

Monolithic Construction With Built In Base-Emitter Shunt Resistors

- High DC Current Gain : $h_{FE}=1000$ @ $V_{CE}=-4V, I_C=-3A$ (Min.)
- Collector-Emitter Sustaining Voltage
- Low Collector-Emitter Saturation Voltage
- Industrial Use
- Complementary to TIP140/141/142

PNP Epitaxial Silicon Darlington Transistor

Equivalent Circuit



Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

| CHARACTERISTICS | SYMBOL | RATING | UNIT |
|---|-----------|--------------------|------------------|
| Collector-Base Voltage : TIP145T : TIP146T : TIP147T | V_{CBO} | -60 -80 -100 | V V V |
| Collector-Emitter Voltage : TIP145T : TIP146T : TIP147T | V_{CEO} | -60 -80 -100 | V V V |
| Emitter-Base Voltage | V_{EBO} | -5 | V |
| Collector Current(DC) | I_C | -10 | A |
| Collector Current(Pulse) | I_{CP} | -15 | A |
| Base Current | I_B | -0.5 | A |
| Collector Dissipation($T_a=25^\circ\text{C}$) | P_C | 2 | W |
| Collector Dissipation($T_c=25^\circ\text{C}$) | P_C | 80 | W |
| Junction Temperature | T_J | 150 | $^\circ\text{C}$ |
| Storage Temperature | T_{STG} | -65~150 | $^\circ\text{C}$ |

TO-220

1. Base
2. Collector
3. Emitter



Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

| CHARACTERISTICS | SYMBOL | Test Condition | Min | Max | Unit |
|--|----------------|---|--------------------|----------------|----------------|
| Collector-Emitter Sustaining Voltage : TIP145T : TIP146T : TIP147T | $V_{CEO(SUS)}$ | $I_C=-30\text{mA}, I_B=0$ | -60 -80 -100 | | V V V |
| Collector Cut-off Current : TIP145T : TIP146T : TIP147T | I_{CEO} | $V_{CE}=-30V, I_B=0$ $V_{CE}=-40V, I_B=0$ $V_{CE}=-50V, I_B=0$ | | -2 -2 -2 | mA mA mA |
| Collector Cut-off Current : TIP145T : TIP146T : TIP147T | I_{CBO} | $V_{CE}=-60V, I_E=0$ $V_{CE}=-80V, I_E=0$ $V_{CE}=-100V, I_E=0$ | | -1 -1 -1 | mA mA mA |
| Emitter Cut-off Current | I_{EBO} | $V_{EB}=-5V, I_C=0$ | | -2 | mA |
| DC Current Gain | h_{FE} | $V_{CE}=-4V, I_C=-5A$ $V_{CE}=-4V, I_C=-10A$ | 1000 500 | | |
| Collector-Emitter Saturation Voltage | $V_{CE(sat)}$ | $I_C=-5A, I_B=-10\text{mA}$ $I_C=-10A, I_B=-40\text{mA}$ | | -2 -3 | V V |
| Base-Emitter ON Voltage | $V_{BE(on)}$ | $V_{CE}=-4V, I_C=-10A$ | | -3 | V |
| Output Capacitance | C_{ob} | $V_{CB}=10V, I_E=0, f=0.1\text{MHz}$ | | 200 | pF |

* Pulse Test: $PW \leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

Typical Characteristics

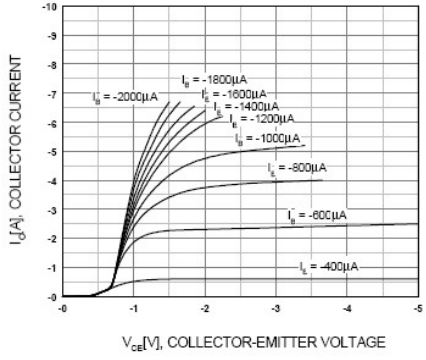


Figure 1. Static Characteristic

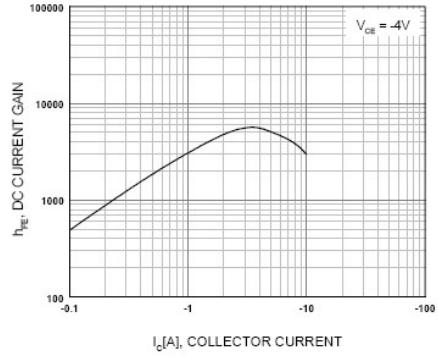


Figure 2. DC current Gain

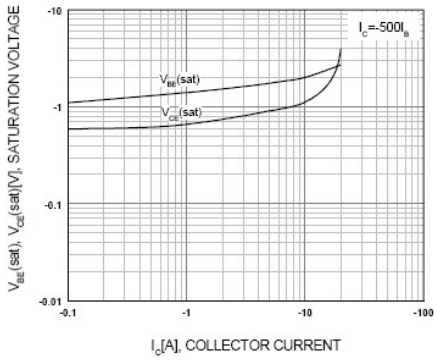


Figure 3. Collector-Emitter Saturation Voltage
Base-Emitter Saturation Voltage

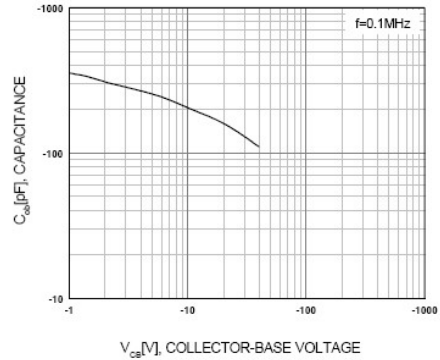


Figure 4. Collector Output Capacitance

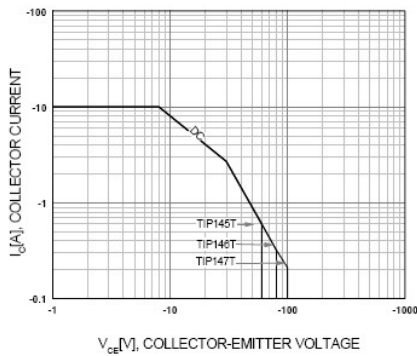


Figure 5. Safe Operating Area

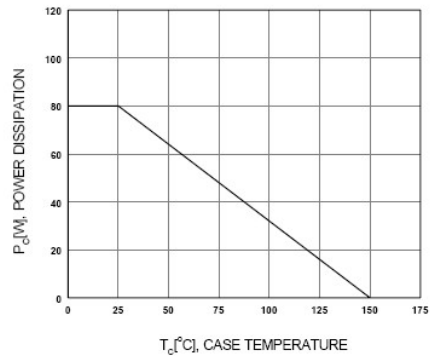
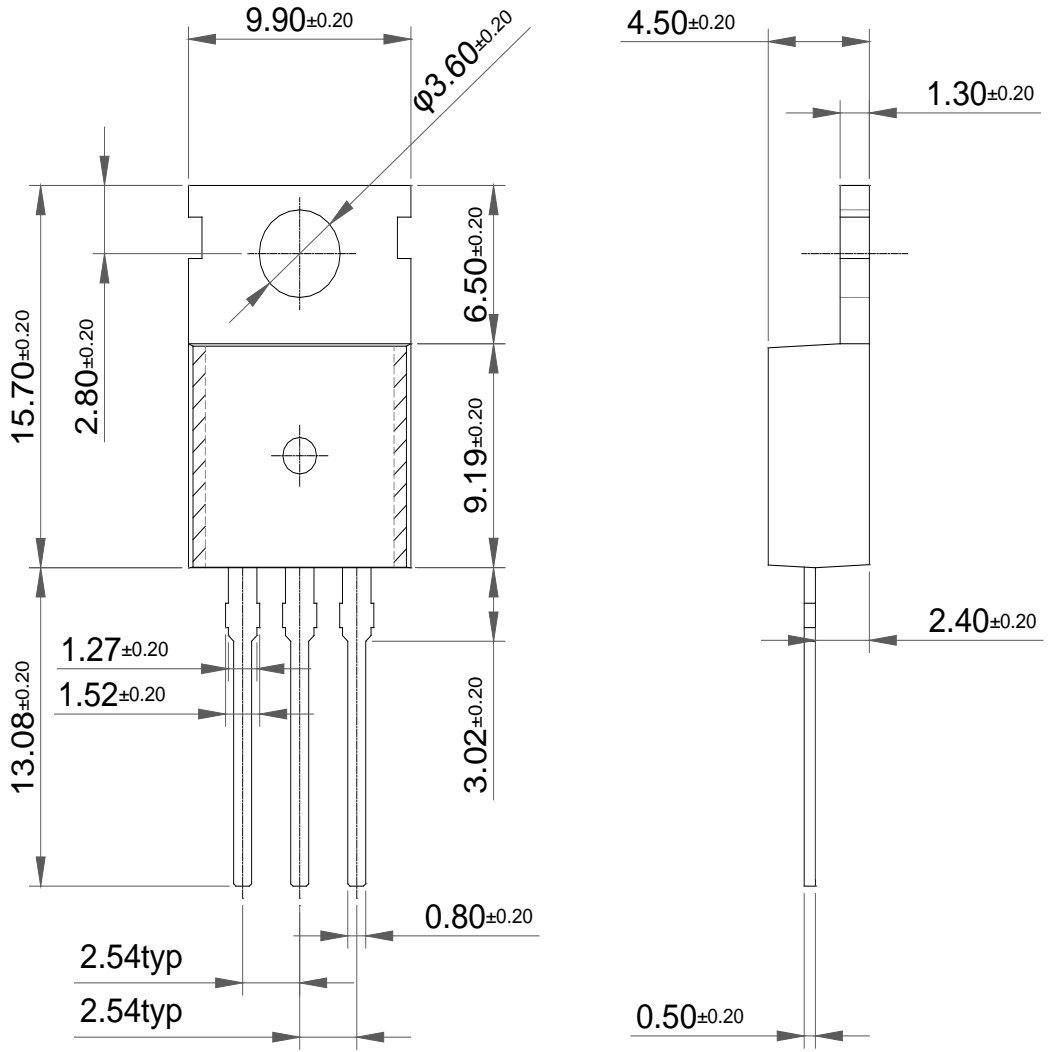


Figure 6. Power Derating

Package Dimension

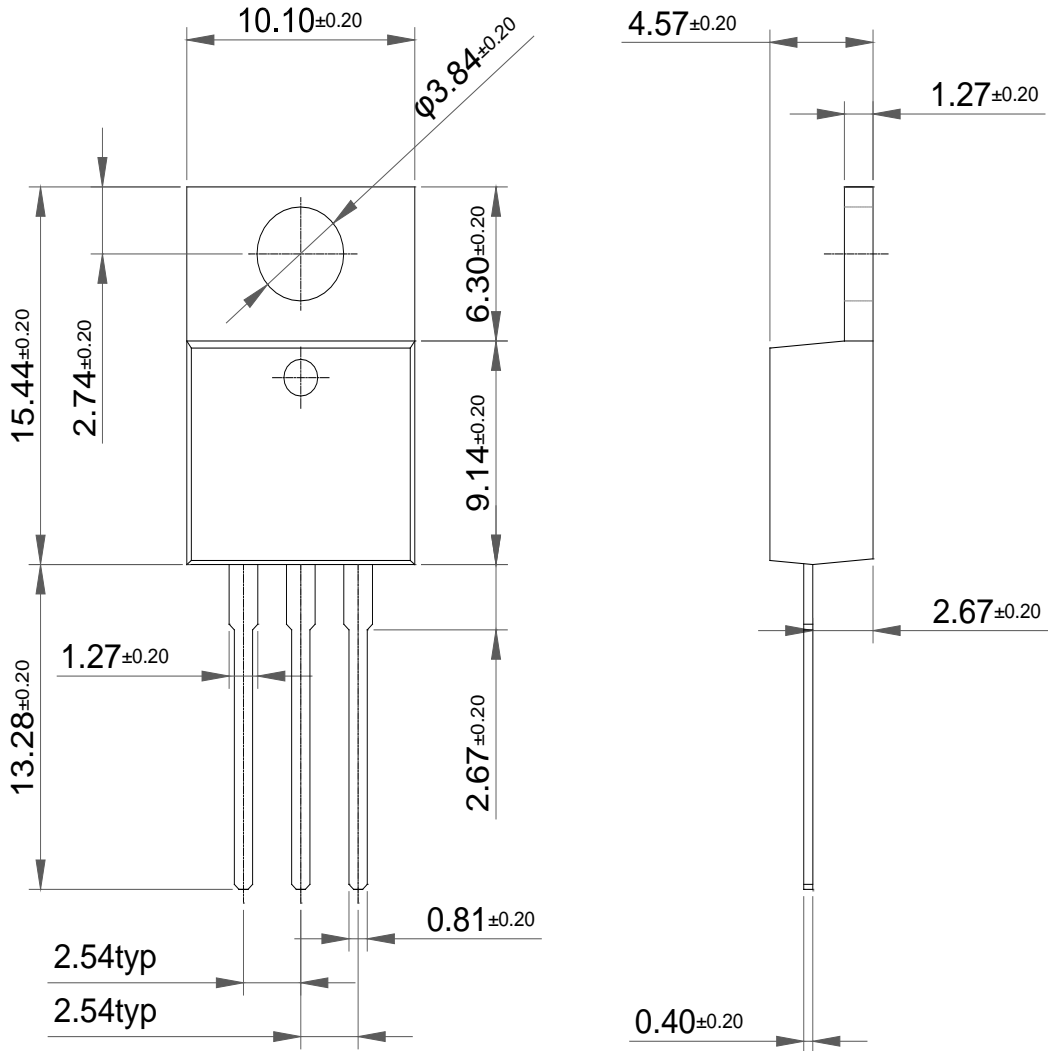
TO-220 (A)



Dimensions in Millimeters

Package Dimension

TO-220 (B)



Dimensions in Millimeters